

1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT54 plastic package intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drivers and microcontrollers
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate

3. Applications

- General purpose low power phase control
- General purpose low power switching
- Solid-state relay

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|--|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 400 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 8 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{lead} ≤ 50 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 0.6 | A |
| Static chara | cteristics | | | | | , |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 1 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 2 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 2 | 5 | mA |





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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------|---|-----|-----|-----|------|
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u> | - | 4 | 7 | mA |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T2 | main terminal 2 | | T2-T1 |
| 2 | G | gate | | Sym051 |
| 3 | T1 | main terminal 1 | | |
| | | | TO-92 (SOT54) | |

6. Ordering information

| Table 3. Ordering in | formation | | |
|----------------------|-----------|---|---------|
| Type number | Package | | |
| | Name | Description | Version |
| MAC97A6 | TO-92 | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |

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7. Limiting values

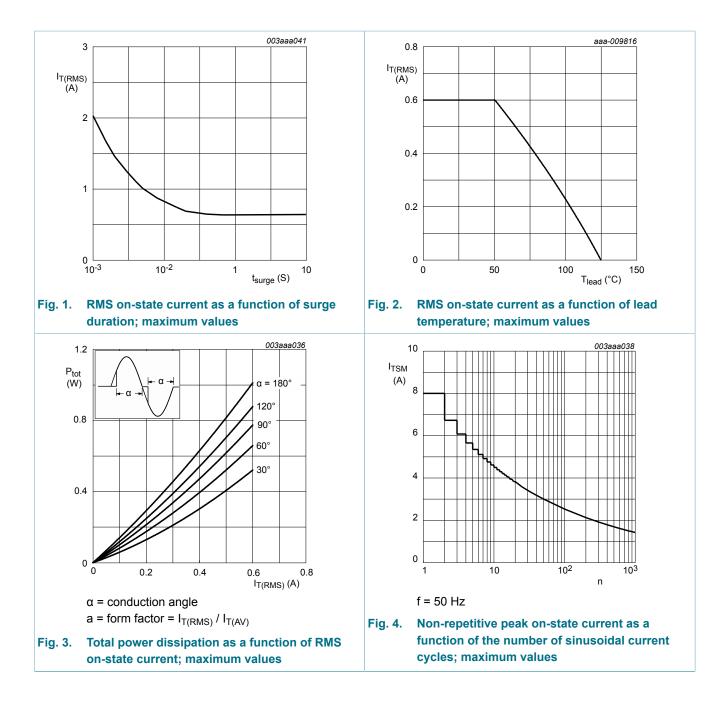
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|------|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 400 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{lead} \le 50$ °C; <u>Fig. 1;</u> Fig. 2; Fig. 3 | - | 0.6 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5 | - | 8 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 8.8 | A |
| l ² t | I2t for fusing | t _p = 10 ms; SIN | - | 0.32 | A ² s |
| dl _T /dt | rate of rise of on-state current | I_T = 1 A; I_G = 20 mA; dI_G/dt = 0.2 A/µs; T2+ G+ | - | 50 | A/µs |
| | | I_T = 1 A; I_G = 20 mA; dI_G/dt = 0.2 A/µs; T2+ G- | - | 50 | A/µs |
| | | I_T = 1 A; I_G = 20 mA; dI_G/dt = 0.2 A/µs; T2- G- | - | 50 | A/µs |
| | | $I_T = 1 \text{ A}; I_G = 20 \text{ mA}; dI_G/dt = 0.2 \text{ A}/\mu\text{s};$ T2- G+ | - | 10 | A/µs |
| I _{GM} | peak gate current | t = 20 microsecs (max) | - | 1 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period ; T(lead) ≤ 80 °C; t = 2 microseconds (max) | - | 0.1 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

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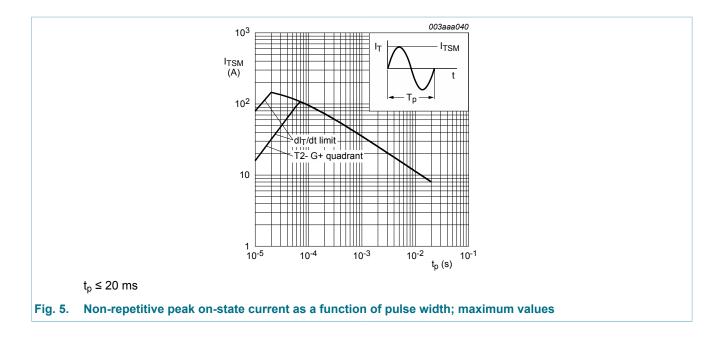
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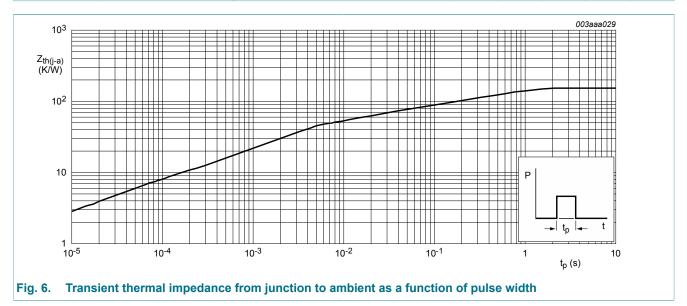
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8. Thermal characteristics

| Table 5. The | rmal characteristics | | | | | |
|-------------------------|---|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-lead)} | thermal resistance from junction to lead | full cycle; <u>Fig. 6</u> | - | - | 60 | K/W |
| | | half cycle | - | - | 80 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | printed circuit board mounted: lead length = 4 mm | - | 150 | - | K/W |



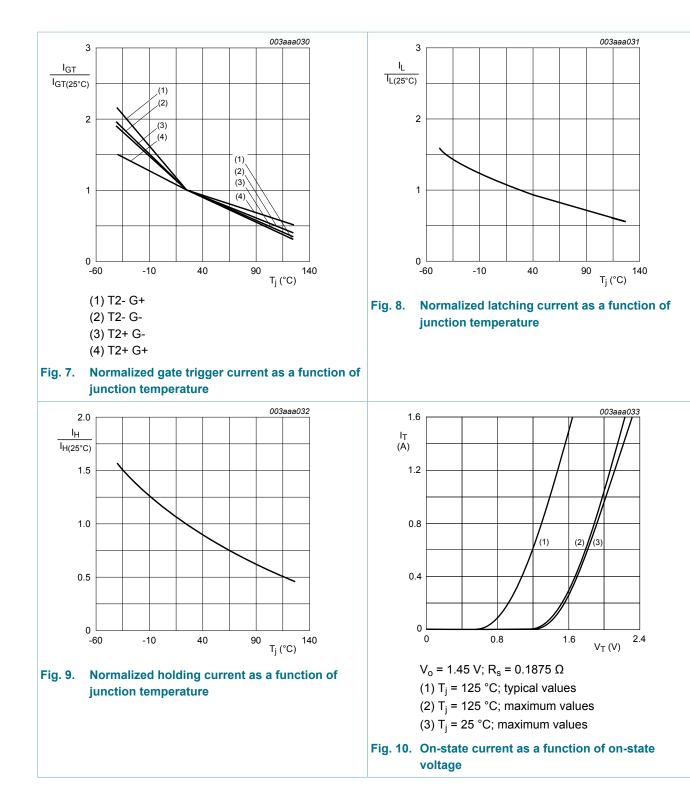
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9. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|-----|-----|-----|------|
| Static chara | octeristics | I I | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 1 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 2 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 2 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 4 | 7 | mA |
| ΙL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C | - | 1 | 10 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | 5 | 10 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | 1 | 10 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 2 | 10 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 1 | 10 | mA |
| V _T | on-state voltage | I _T = 0.85 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.9 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.9 | 1.5 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 110 °C; Fig. 11 | 0.1 | 0.7 | - | V |
| l _D | off-state current | V _D = 400 V; T _j = 110 °C | - | 3 | 100 | μA |
| Dynamic ch | aracteristics | · · · · · · · · · · · · · · · · · · · | I | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 268 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12 | 30 | 45 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T _j = 50 °C; dI _{com} /dt = 0.3 A/ ms; I _T = 0.84 A; gate open circuit | - | 5 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 1 A; V_D = 400 V; I_G = 25 mA; dI_G/dt = 5 A/µs | - | 2 | - | μs |

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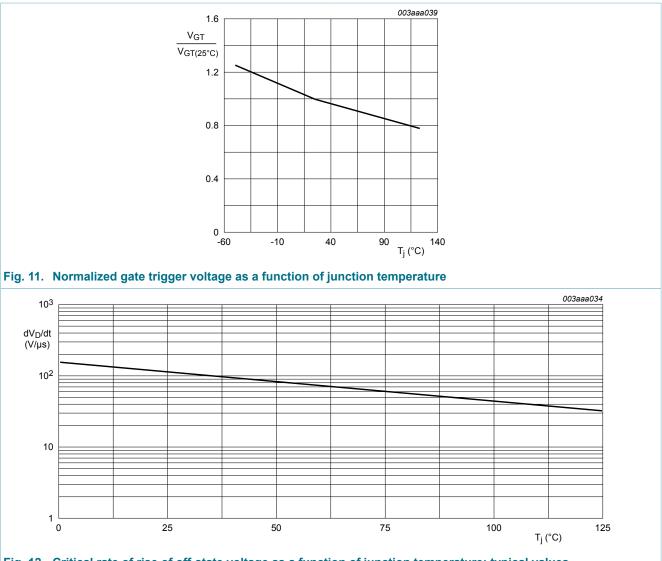


Fig. 12. Critical rate of rise of off-state voltage as a function of junction temperature; typical values

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10. Package outline

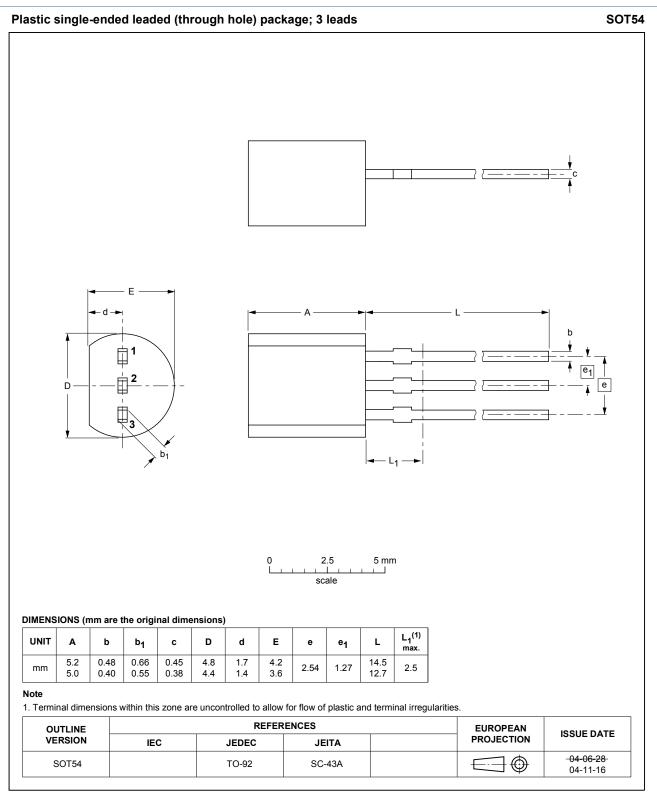


 Fig. 13. Package outline TO-92 (SOT54)

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Product data sheet

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11. Legal information

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|--------------------------------------|-------------------------------|---|
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